

Description

The 74AHCT1G32Q is an automotive compliant single, two-input positive NAND gate with a standard push-pull output. The device is designed for operation with a power supply range of 4.5V to 5.5V. The gate performs the positive Boolean function:

$$Y = A + B \text{ or } Y = \overline{\overline{A} \cdot \overline{B}}$$

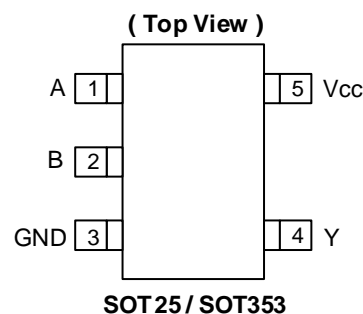
Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 4.5V to 5.5V
- ±8mA Output Drive at 5.0V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs Not Limited by Vcc
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The 74AHCT1G32Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



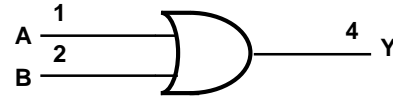
Applications

- General Purpose Logic
- Wide Array of Products, such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

Pin Descriptions

Pin Name	Description
A	Data Input
B	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

Logic Diagram



Function Table

Inputs		Output
A	B	Y
H	X	H
X	H	H
L	L	L

Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
V _I	Input Voltage Range	-0.5 to 6.5	V
V _O	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} + 0.5	V
I _{IK}	Input Clamp Current V _I < 0	-20	mA
I _{OK}	Output Clamp Current (V _O < 0 or V _O > V _{CC})	±20	mA
I _O	Continuous Output Current (V _O = 0 to V _{CC})	±25	mA
I _{CC}	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
T _J	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _D	Total Power Dissipation (Note 6)	250	mW

- Notes:
- Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
 - Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.
 - This will need to be derated at higher operating temperatures to prevent exceeding maximum T_J. Refer to package thermal characteristics section.

Recommended Operating Conditions (Note 7)

Symbol	Parameter		Min	Max	Unit
V _{CC}	Operating Voltage	—	4.5	5.5	V
V _{IH}	High-Level Input Voltage	V _{CC} = 5V ± 0.5V	2.0	—	V
V _{IL}	Low-Level Input Voltage	V _{CC} = 5V ± 0.5V	—	0.8	V
V _I	Input Voltage	—	0	5.5	V
V _O	Output Voltage	—	0	V _{CC}	V
I _{OH}	High-Level Output Current	V _{CC} = 5V ± 0.5V	—	-8	mA
I _{OL}	Low-Level Output Current	V _{CC} = 5V ± 0.5V	—	8	mA
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 5V ± 0.5V	—	20	ns/V
T _A	Ambient Temperature	—	-40	+125	°C

Note: 7. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (All typical values are at V_{CC} = 5V, T_A = +25°C.)

Symbol	Parameter	Test Conditions	V _{CC}	+25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V _{OH}	High Level Output Voltage	V _I = V _{IH} or V _{IL} I _{OH} = -50μA	4.5V	4.4	4.5	—	4.4	—	4.4	—	V
		V _I = V _{IH} or V _{IL} I _{OH} = -8mA	4.5V	3.94	—	—	3.8	—	3.70	—	V
V _{OL}	Low Level Output Voltage	V _I = V _{IH} or V _{IL} I _{OL} = 50μA	4.5V	—	0	0.1	—	0.1	—	0.1	V
		V _I = V _{IH} or V _{IL} I _{OL} = 8mA	4.5V	—	—	0.36	—	0.44	—	0.55	V
I _I	Input Current	V _I = 5.5V or GND	0 to 5.5V	—	—	±0.1	—	±1	—	±2	μA
ΔI _{CC}	Additional Supply Current	Per input pin; V _I = 3.4V; other inputs at V _{CC} or GND; I _O = 0	5.5V	—	—	1.35	—	1.5	—	1.5	mA
I _{CC}	Supply Current	V _I = 5.5V or GND I _O = 0	5.5V	—	—	1	—	10	—	40	μA
C _I	Input Capacitance	V _I = V _{CC} or GND	5.5V	—	1.5	10	—	10	—	10	pF

Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Typ	Max	Unit
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT25	Note 8	—	184	—	°C/W
		SOT353		—	385	—	
θ_{JC}	Thermal Resistance Junction-to-Case	SOT25	Note 8	—	62	—	°C/W
		SOT353		—	164	—	

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

V_{CC} = 5V ± 0.5V (See Figure 1, Typical values at V_{CC} = 5V.)

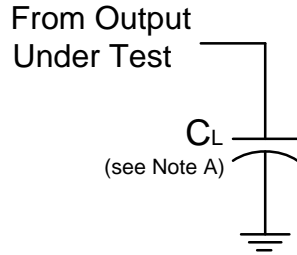
Parameter	From (Input)	To (Output)	Test Conditions	+25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t _{PD}	A or B	Y	C _L = 15pF	1.0	3.3	6.9	1.0	8.0	1.0	9.0	ns
			C _L = 50pF	1.0	4.8	7.9	1.0	9.0	1.0	10.0	ns

Operating Characteristics

T_A = +25°C

Parameter	Test Conditions	V _{CC} = 5V	Unit
		Typ	
C _{PD}	f = 1MHz No Load	10	pF

Measurement Information



Vcc	Inputs			Output	CL
	VI	tr/tf	VM	VM	
5V±0.5V	GND to Vcc	≤3ns	1.5V	Vcc/2	15pF
5V±0.5V	GND to Vcc	≤3ns	1.5V	Vcc/2	50pF

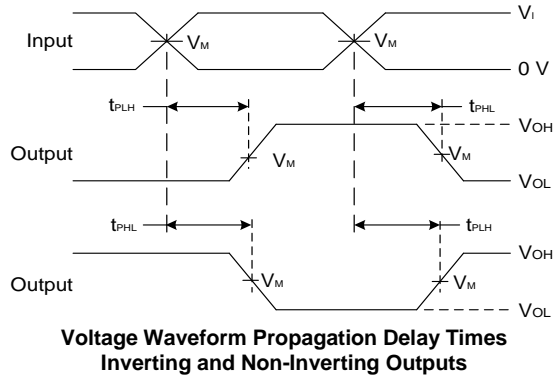
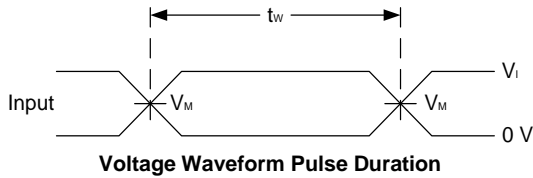
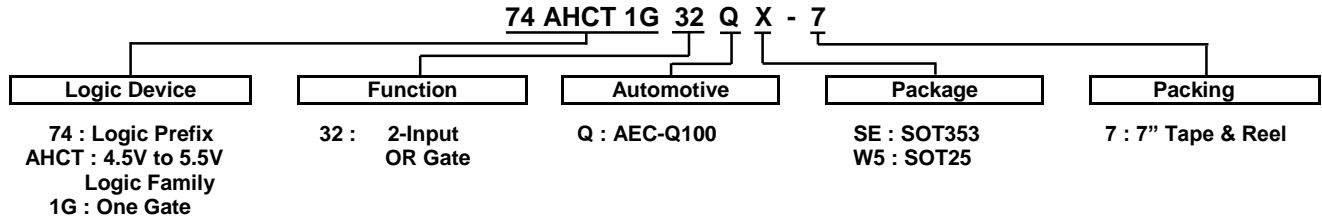


Figure 1. Load Circuit and Voltage Waveforms

- Notes:
- A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate ≤ 1MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as t_{PD} .

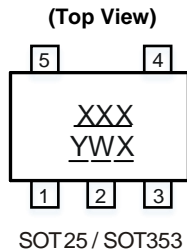
Ordering Information (Note 9)



Part Number	Package Code	Package (Notes 10 & 11)	Package Size	7" Tape and Reel	
				Quantity	Part Number Suffix
74AHCT1G32QSE-7	SE	SOT353	2.15mm × 2.1mm × 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7
74AHCT1G32QW5-7	W5	SOT25	3.0mm × 2.8mm × 1.2mm 0.95mm lead pitch	3000/Tape & Reel	-7

Notes: 9. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.
 10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at <http://www.diodes.com/package-outlines.html>.
 11. The taping orientation is located on our website at <https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf>.

Marking Information



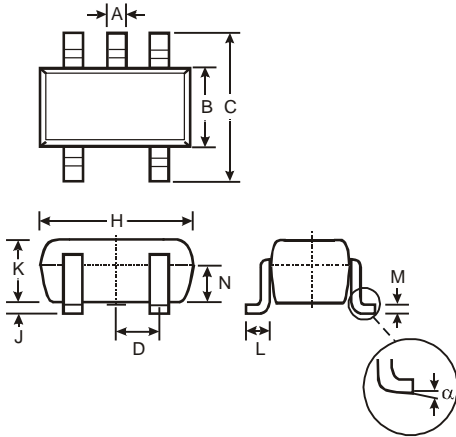
XXX : Identification Code
 Y : Year 0-9
 W : Week: A~Z 1~26 week
 a~z 27~52 week
 z represents week 52 and 53
 X : A~Z: Internal Code

Part Number	Package	Identification Code
74AHCT1G32QW5-7	SOT25	ZWQ
74AHCT1G32QSE-7	SOT353	ZWQ

Package Outline Dimensions

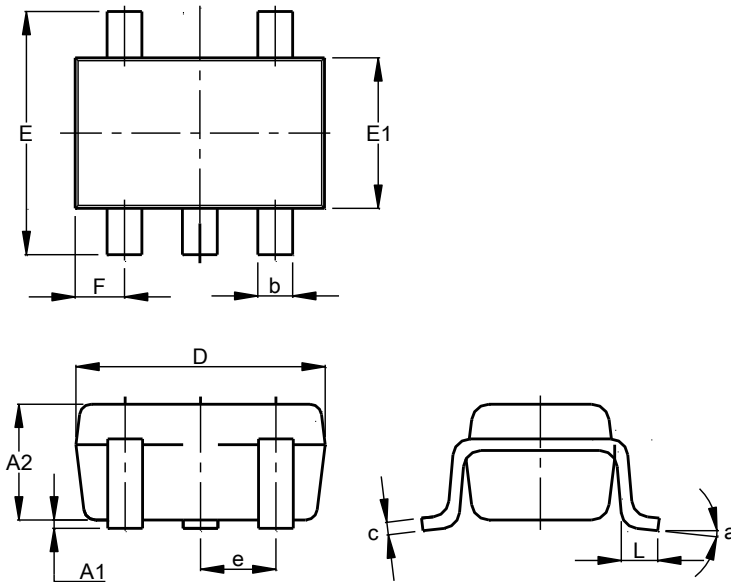
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) Package Type: SOT25



SOT25			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	-	-	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All Dimensions in mm			

(2) Package Type: SOT353

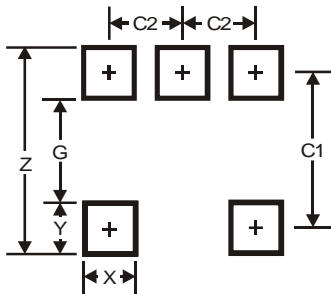


SOT353			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

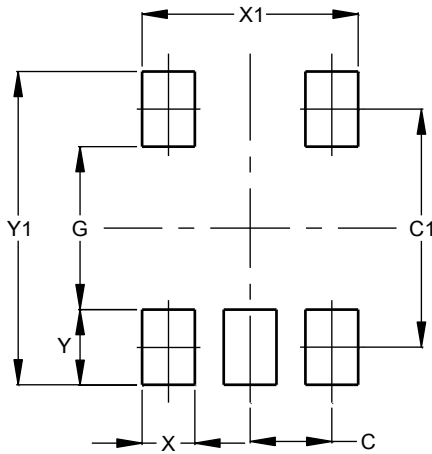
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)
C	0.650
C1	1.900
G	1.300
X	0.420
X1	1.720
Y	0.600
Y1	2.500

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight: 0.0064 grams (Approximate)

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